UNISONIC TECHNOLOGIES CO., LTD

18N60 **Power MOSFET**

18A,600V N-CHANNEL POWER MOSFET

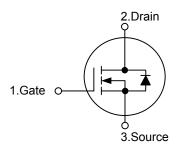
DESCRIPTION

The UTC 18N60 uses UTC's advanced proprietary, planar stripe, DMOS technology to provide excellent R_{DS(ON)}, low gate charge and operation with low gate voltages. This device is suitable for use as a load switch or in PWM applications.

FEATURES

- * $R_{DS(ON)} \le 0.5\Omega$ @ V_{GS} =10V, I_D =9A
- * Ultra Low Gate Charge (Typical 50nC)
- * Low Reverse Transfer Capacitance (C_{RSS} = Typical 23pF)
- * Fast Switching Capability
- * Avalanche Energy Specified
- * Improved dv/dt Capability, High Ruggedness

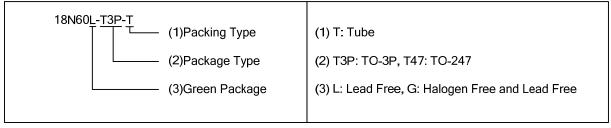




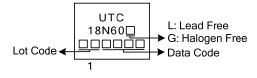
ORDERING INFORMATION

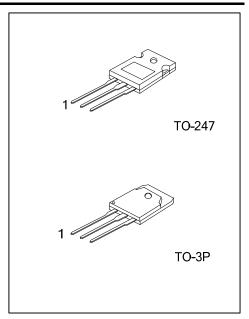
Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
18N60L-T3P-T	18N60G-T3P-T	TO-3P	G	D	S	Tube	
18N60L-T47-T	18N60G-T47-T	TO-247	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source



MARKING





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■ ABSOLUTE MAXIMUM RATINGS (T_C =25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V_{DSS}	600	V	
Gate-Source Voltage		V_{GSS}	±30	V	
Continuous Drain Current		I _D	18	А	
Pulsed Drain Current		I _{DM}	45	А	
Avalanche Current		I _{AR}	18	А	
Avalanche Energy	Single Pulsed	E _{AS}	1000 (Note 2)		
	Repetitive	E _{AR}	30	mJ	
Peak Diode Recovery dv/dt		dv/dt	10	V/ns	
Power Dissipation	TO-247	Б	360	W	
	TO-3P	P _D	395	W	
Junction Temperature		TJ	150	°C	
Storage Temperature		T _{STG}	-55 ~ +150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient	TO-247	0	40	°C/W	
	TO-3P	θμΑ	30		
Junction to Case	TO-247	0	0.35	°C/W	
	TO-3P	$ heta_{ extsf{jC}}$	0.32		

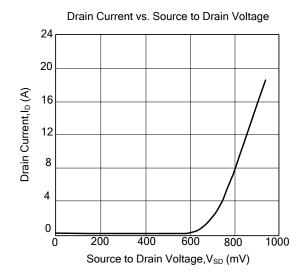
^{2.} L=6.18mH, I_{AS} =18A, V_{DD} =50V, R_{G} =25 Ω , Starting T_{J} =25 $^{\circ}$ C

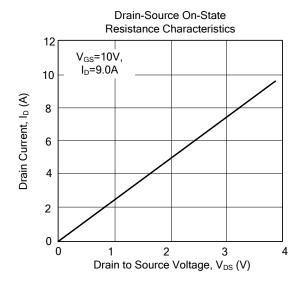
■ **ELECTRICAL CHARACTERISTICS** (T_J =25°C, unless otherwise specified)

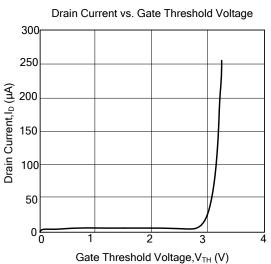
PARAMETER	SYMBOL	TEST CONDITIONS MIN TYP		TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage	BV _{DSS}	V_{GS} =0V, I_D =250 μ A	600			V		
Drain-Source Leakage Current	I _{DSS}	V _{DS} =600V, V _{GS} =0V			25	μΑ		
Gate-Body Leakage Current	I _{GSS}	V_{DS} =0V, V_{GS} =±30V			±100	nA		
ON CHARACTERISTICS								
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.0		4.0	V		
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =9A (Note)		0.36	0.5	Ω		
DYNAMIC PARAMETERS								
Input Capacitance	C _{ISS}			2500		pF		
Output Capacitance	Coss	V_{DS} =25V, V_{GS} =0V, f=1MHz		280		pF		
Reverse Transfer Capacitance	C _{RSS}			23		pF		
SWITCHING PARAMETERS								
Turn-ON Delay Time	t _{D(ON)}			21		ns		
Turn-ON Rise Time	t _R	V_{GS} =10V, V_{DS} =0.5 V_{DSS} ,		22		ns		
Turn-OFF Delay Time	t _{D(OFF)}	I _D =18A, R _G =5Ω (External)		62		ns		
Turn-OFF Fall-Time	t _F			22		ns		
Total Gate Charge	Q_{G}			50		nC		
Gate Source Charge	Q_GS	V_{GS} =10V, V_{DS} =0.5 V_{DSS} , I_{D} =9A		15		nC		
Gate Drain Charge	Q_GD			18		nC		
SOURCE- DRAIN DIODE RATINGS AN	D CHARACTE	RISTICS						
Drain-Source Diode Forward Voltage	V_{SD}	I _F =I _S ,V _{GS} =0V (Note)			1.5	V		
Maximum Continuous Drain-Source	-	V _{GS} =0V			18	Α		
Diode Forward Current	I _S				10	А		
Maximum Pulsed Drain-Source Diode	la	Repetitive			54	Α		
Forward Current	I _{SM}				04	^		
Reverse Recovery Time	t _{rr}	V _{GS} =0V, dI _F /dt=100A/μs,			200	ns		
Reverse Recovery Charge Q _R		I _S =18A, V _R =100V		0.8		μC		
N . D . T . D . M"								

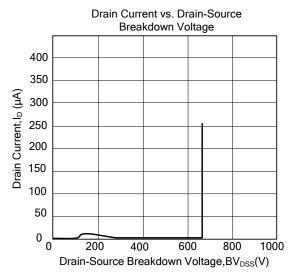
Note: Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.

■ TYPICAL CHARACTERISTICS









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